



OVERVIEW

The SM9501A is a BiCMOS RCC*1 receiver IC. It accepts low frequency standard wave input received from an external antenna, amplifies it, detects the data signal, and outputs a digital time code signal.

FEATURES

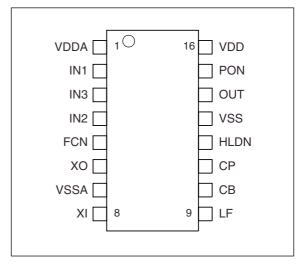
- Operating supply voltage range: 2.4 to 3.6V
- Operating current consumption: 55µA (typ) @3V
- Standby current consumption: 0.1µA (max) @3V
- High sensitivity: 0.5µVrms input
- Wide frequency range (35kHz to 80kHz)
- Include analog switch for antennatuning capacitors change
- AGC gain hold function
- External crystal filter connection
- BiCMOS process
- Package:16-pin VSOP, Chip form

ORDERING INFORMATION

Device	Package
SM9501AV	16-pin VSOP
CF9501A	Chip form

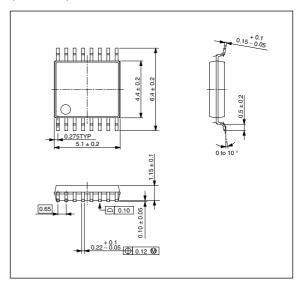
PINOUT

(Top view)



PACKAGE DIMENSIONS

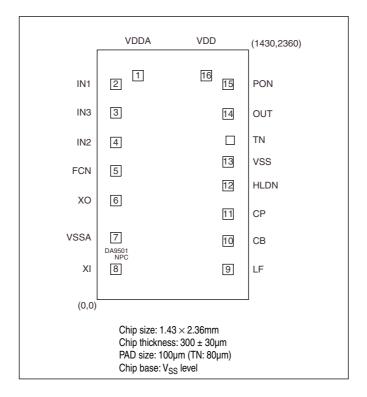
(Unit: mm)



^{*1:} Radio controlled clock

PAD LAYOUT (CF9501A)

(Unit: µm)

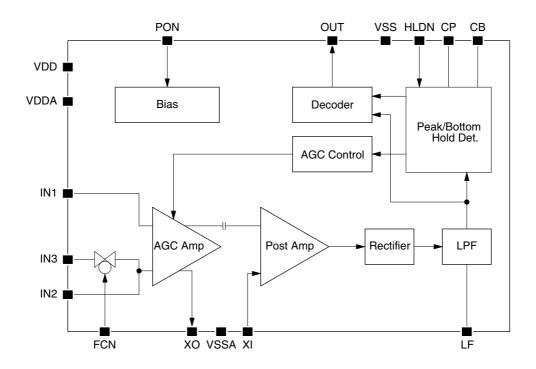


PAD NAME and DIMENSIONS (CF9501A)

Pad number	Pad name	Pad dimen	sions [µm]
Pad number	Pad name	Х	Y
1	VDDA	386	2117
2	IN1	177	2035
3	IN3	177	1766
4	IN2	177	1486
5	FCN	177	1217
6	ХО	177	937
7	VSSA	177	586
8	XI	177	288
9	LF	1237	286
10	СВ	1237	555
11	СР	1237	809
12	HLDN	1237	1078
13	VSS	1237	1302
14	OUT	1237	1755
15	PON	1237	2035
16	VDD	1031	2117
_	TN ¹	1257	1506

^{1.} For test mode

BLOCK DIAGRAM



PIN DESCRIPTION

Number	Name	I/O ¹	A/D ²	Description
1	VDDA	-	A	AGC amplifier (+) supply input
2	IN1	I	А	Antenna input 1 (fixed input)
3	IN3	I	A	Antenna input 3 (via analog switch)
4	IN2	I	A	Antenna input 2 (analog switch bypass)
5	FCN	lpu	D	Analog switch control input (active LOW)
6	ХО	0	A	Output for crystal filter
7	VSSA	-	A	AGC amplifier (–) supply input
8	XI	I	A	Input from crystal filter
9	LF	0	А	Rectifier LPF capacitor connection
10	СВ	0	A	Bottom hold detector capacitor connection
11	СР	0	A	Peak hold detector capacitor connection
12	HLDN	lpu	D	AGC gain hold control (active LOW)
13	VSS	-	А	Substrate (–) supply input
14	OUT	0	D	Clock time code output (active LOW)
15	PON	lpu	D	Standby state control input (active LOW)
16	VDD	-	A	(+) supply input
_	TN	lpu	D	AGC amplifier gain control switch (active LOW, for test mode)

^{1.} I: input, O: output, Ipu: input with pull-up resistor, $\mathord{\text{--}}$ supply pin

^{2.} A: analog signal, D: digital signal

SPECIFICATIONS

Absolute Maximum Ratings

$$V_{SS} = 0V$$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V _{DD}		-0.3 to +7.0	V
Input voltage range	V _{IN}	-0.3 to V _{DD} +0.3		٧
Power dissipation	P _D	16-pin VSOP	150	mW
Storage temperature range	_	16-pin VSOP	-55 to +125	°C
Storage temperature range	I stg	Chip form	-65 to +150	°C

Note. Absolute maximum ratings are the values that must never exceed even for a moment. The device may be damaged or deteriorated the characteristics or reliability if these parameter ratings are exceeded.

Recommended Operating Conditions

$$V_{SS} = 0V$$

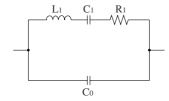
Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	V _{DD}		2.4 to 3.6	V
Operating temperature range	T _{opr}		-20 to +70	°C

Electrical Characteristics

 $V_{\rm DD}$ = 2.4 to 3.6V, $V_{\rm SS}$ = 0V, Ta = -20 to +70°C unless otherwise noted.

Supply voltage V_{DD} V_{D	Parameter	Symbol	Condition		Rating	Unit	
Maximum operating current consumption IoDM VoD = 3.0V, Ta = 25°C, no input signal, PON: VSS, OUT: no load DON: V	Parameter	Symbol	Condition	min	typ	max	Unit
consumption¹ PON: VSS, OUT: no load — 69 100 μη Operating current consumption¹ I _{DDT} V _{DD} = 3.0V, Ta = 25°C, Ontw/ms input amplitude (differential input), 500ms pulsewidth, PON: VSS, OUT: no load — 55 — μΑ Standby mode current consumption I _{ST} V _{DD} = V _{DDA} = 3.6V, PON, FCN, HLDN: OPEN, OUT: no load — — 0.1 μΑ Minimum input voltage range V _{fmin} IN1-IN2 differential input, f _{IN} = 40kHz, 60kHz, 1 a = 25°C 80 — — mV/mms Maximum input voltage range V _{fmax} IN1-IN2 differential input, f _{IN} = 40kHz, 60kHz, 60kHz, 1 a = 25°C 80 — — mV/mms Input frequency f _{IN} IN1-IN2 differential input, f _{IN} = 40kHz, 60kHz, 60kHz	Supply voltage	V_{DD}		2.4	3.0	3.6	٧
Operating current consumption 1 operating current consumption 1 operating current consumption 1 operating current consumption 2 operating current consumption 3 operating current consumption 2 operating current consumption 3 operating current 2 operating current 3 operating current 4 operating current 5 opera	1, 0	I _{DDM}		-	65	100	μA
Minimum input voltage range V _{fmin} Int	Operating current consumption ¹	I _{DDT}	0.1mVrms input amplitude (differential input), 500ms pulsewidth,	-	55	-	μА
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Standby mode current consumption	I _{ST}	V _{DD} = V _{DDA} = 3.6V, PON, FCN, HLDN: OPEN, OUT: no load	-	-	0.1	μА
$ \begin{array}{ c c c c c } \hline \ \ \ \ \ \ \ \ \ \ \ \ \$	Minimum input voltage range	V_{fmin}		-	0.5	1.0	μVrms
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Maximum input voltage range	V_{fmax}	IN1-IN2 differential input, f _{IN} = 40kHz, 60kHz	80	-	-	mVrms
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Input frequency	f _{IN}	IN1-IN2 differential input	35	-	80	kHz
Startup time² (PON) t _{PON} From standby mode - - 8 sec Input voltage V _{IL} V _{IL} PON, FCN, HLDN pins - - 0.5 V Input current IIL V _{IL} = 0V, PON, FCN, HLDN pins - -0.5 -1.5 μA LOW-level output current I I _{IH} V _{IL} = 0V, PON, FCN, HLDN pins - - 1 μA LOW-level output current I O _L OUT pin, V _{OL} = V _{SS} + 0.5V 10 - - μA Gain hold time t _{HLD} ± 3dB change 1 - - - μA Fall time output propagation delay³ t _{DN} ± 3dB change 1 - - 160 ms Eight ime output propagation delay³ t _{DN} t _{DN} - - 160 ms LOW-level output pulsewidth⁴ (200ms) T ₂₀₀ t _{IN} = 40kHz, 60kHz, Ta = 25°C, V _{IN} = 1μVrms to 80mVrms, NC standard ging 400 500 650 ms LOW-level output pulsewidth⁴ (800ms) T ₂₀₀ T ₂₀₀	Analog switch resistance	R _A	V _{IN2} = 0V, V _{IN3} = 50mV	-	-	15	Ω
$ \begin{array}{c} I_{1DUt} \ voltage \\ I$	Startup time ²	t _{ON}	When supply is applied	-	-	8	sec
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Startup time ² (PON)	t _{PON}	From standby mode	-	-	8	sec
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Input voltage	V _{IL}	PON ECN HIDN pins	-	_	0.5	V
$ \begin{array}{ c c c c c } \hline \text{Input current} & I_{\text{IH}} & V_{\text{IH}} = V_{\text{DD}}, \text{PON, FCN, HLDN pins} & - & - & 1 & \mu A \\ \hline \text{LOW-level output current} & I_{\text{OL}} & \text{OUT pin, } V_{\text{OL}} = V_{\text{SS}} + 0.5V & 10 & - & - & \mu A \\ \hline \text{HIGH-level output current} & I_{\text{OH}} & \text{OUT pin, } V_{\text{OH}} = V_{\text{DD}} - 0.5V & -10 & - & - & \mu A \\ \hline \text{Gain hold time} & t_{\text{HLD}} & \pm 3\text{dB change} & 1 & - & - & \text{sec} \\ \hline \text{Fall time output propagation delay}^3 & t_{\text{DN}} & - & - & 160 & \text{ms} \\ \hline \text{Rise time output propagation delay}^3 & t_{\text{UP}} & - & - & 200 & \text{ms} \\ \hline \text{LOW-level output pulsewidth}^4 \text{ (200ms)} & T_{200} & \\ \hline \text{LOW-level output pulsewidth}^4 \text{ (500ms)} & T_{500} & \\ \hline \text{LOW-level output pulsewidth}^4 \text{ (800ms)} & T_{800} & \\ \hline \end{array}$	input voitage	V _{IH}	FON, FON, FIEDIN PINS	V _{DD} -0.5	_	-	V
	Input ourront	I _{IL}	V _{IL} = 0V, PON, FCN, HLDN pins	-	-0.5	-1.5	μA
HIGH-level output current I_{OH} OUT pin, $V_{OH} = V_{DD} - 0.5V$ -10 $ \mu A$ Gain hold time t_{HLD} $\pm 3dB$ change 1 $ -$ sec Fall time output propagation delay ³ t_{DN} Rise time output propagation delay ³ t_{UP} $ -$ 160 ms LOW-level output pulsewidth ⁴ (200ms) T_{200} $t_{IN} = 40kHz$, $60kHz$, $Ta = 25^{\circ}C$, $V_{IN} = 1\mu Vrms$ to $80mVrms$, NPC standard gig $V_{IN} = 1\mu Vrms$ to	input current	I _{IH}	$V_{IH} = V_{DD}$, PON, FCN, HLDN pins	-	-	1	μA
Gain hold time $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	LOW-level output current	I _{OL}	OUT pin, V _{OL} = V _{SS} + 0.5V	10	_	-	μA
Fall time output propagation delay ³ t_{DN} Rise time output propagation delay ³ t_{UP} LOW-level output pulsewidth ⁴ (200ms) T_{200} LOW-level output pulsewidth ⁴ (500ms) T_{500} LOW-level output pulsewidth ⁴ (800ms) T_{800} T_{800} To a compare the control of the co	HIGH-level output current	I _{OH}	OUT pin, $V_{OH} = V_{DD} - 0.5V$	-10	_	-	μA
Rise time output propagation delay ³ t_{UP} LOW-level output pulsewidth ⁴ (200ms) T_{200} LOW-level output pulsewidth ⁴ (500ms) T_{500} LOW-level output pulsewidth ⁴ (800ms) T_{800} NPC standard crystal, NPC standard jig T_{800} T_{800} T_{800} T_{800} T_{800} T_{800} T_{800} T_{800} T_{800}	Gain hold time	t _{HLD}	± 3dB change	1	-	-	sec
LOW-level output pulsewidth ⁴ (200ms) T_{200} $T_{1N} = 40$ kHz, 60 kHz, $T_{1N} = 25$ °C, $T_{1N} = 1$ µVrms to 1 0 $T_{1N} = 1$ 0	Fall time output propagation delay ³	t _{DN}		-	-	160	ms
LOW-level output pulsewidth ⁴ (800ms) T_{500} $V_{IN} = 1 \mu V r ms$ to 80mVrms, NPC standard crystal, NPC standard jig 400 500 650 ms T_{800}	Rise time output propagation delay ³	t _{UP}		-	-	200	ms
LOW-level output pulsewidth ⁴ (500ms) T ₅₀₀ NPC standard crystal, NPC standard jig 400 500 650 ms LOW-level output pulsewidth ⁴ (800ms) T ₈₀₀ 700 800 900 ms	LOW-level output pulsewidth ⁴ (200ms)	T ₂₀₀		100	200	300	ms
	LOW-level output pulsewidth ⁴ (500ms)	T ₅₀₀		400	500	650	ms
Noise rejection ratio ⁵ S/N – – 9 dB	LOW-level output pulsewidth ⁴ (800ms)	T ₈₀₀		700	800	900	ms
	Noise rejection ratio ⁵	S/N		-	-	9	dB

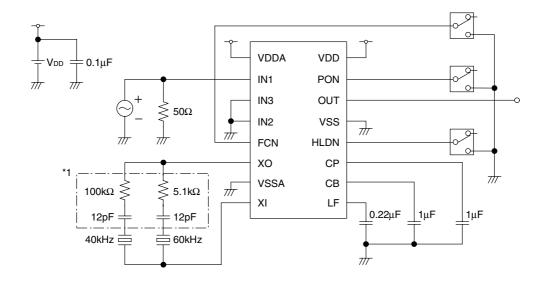
- 1. Measured using the standard circuit.
- 2. The time taken under stable wave input conditions from when power is applied or standby is released, using PON, until stable digital output occurs within ratings.
- 3. The time taken, with 10:1 input signal amplitude ratio and 500ms pulsewidth, from when a change in signal input amplitude occurs until the output OUT changes. Note that this characteristic is very dependent on the antenna and crystal filter characteristics. The standard crystal used for crystal filter by our measurement has the following equivalent circuit coefficients as reference values.



f [kHz]	L1 [kH]	C1 [fF]	R 1 [kΩ]	C0 [pF]
40	6.70280	2.36228	11.4492	1.42773
60	5.17396	1.36007	13.4826	1.04927

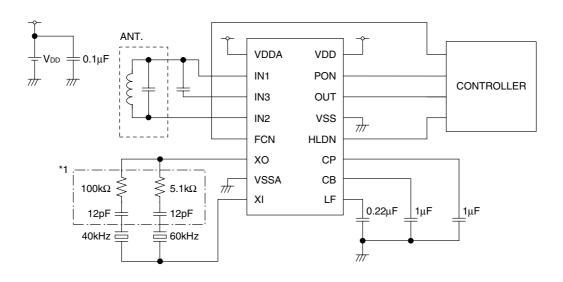
- 4. Values obtained when using the crystal filter employed here. Note that these values are dependent on the crystal characteristics, and should be considered as reference values.
- 5. Time averaged rms values, where the noise is white noise and the measurement bandwidth is determined by the crystal filter equivalent used in the standard circuit. Note that this value is very dependent on the crystal filter characteristics used.

STANDARD CIRCUIT



*1. These values are obtained when using NPC's standard crystal and should be considered as reference values. In case of using different crystal, the values are different.

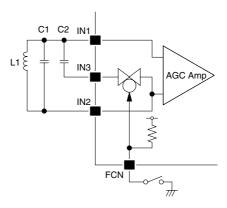
APPLICATION CIRCUIT



*1. These values are obtained when using NPC's standard crystal and should be considered as reference values. In case of using different crystal, the values are different.

FUNCTIONAL DESCRIPTION

Antenna Input and Tuning Capacitor Switching Function



There are three antenna inputs: IN1, IN2, and IN3. When FCN is open (or HIGH), the internal analog switch is OFF and IN1–IN2 are the antenna inputs (60kHz mode). When FCN is LOW, the analog switch is ON, connecting IN3 and IN2. C2 is then connected in parallel to C1 in the tuning circuit, reducing the resonant frequency (40kHz mode).

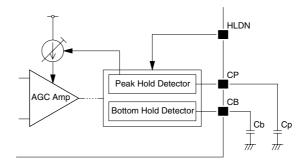
FCN	Analog switch	Antenna input	Tuning capacitor	Receiver frequency
Open or HIGH	OFF	Between IN1 and IN2	C1	60kHz
LOW	ON	Between IN1 and IN2, IN3	C1 + C2 parallel	40kHz

FCN should be left open if not using the tuning capacitor switching function, and IN2 should be connected to IN3 externally.

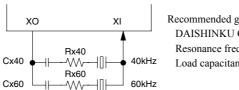
AGC Amplifier and Gain Hold Function

The input voltage from the antenna is amplified by the AGC amplifier. The gain can be monitored by the voltage on pin CP, and can be changed by varying the CP voltage. An external capacitor Cp can be connected to CP to stabilize the voltage, but the gain tracking time is dependent on the capacitance. When HLDN is open (or HIGH), the gain automatically adjusts to follow the post-amplifier detector signal. When HLDN is LOW, the immediately preceding gain is held for an interval determined by the Cp capacitance.

HLDN	Gain tracking
Open or HIGH	Auto tracking
LOW	Gain held fixed



Crystal Filter Circuit



Recommended goods(Crystal filter)
DAISHINKU CORP.: DT-261

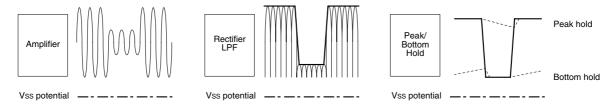
Resonance frequency: 40.000kHz/60.000kHz

Load capacitance: 12.5pF±25ppm

External crystals are used as filters. Multiple frequencies (40kHz and 60kHz) are supported by connecting crystals in parallel. The center frequency and bandwidth of the filters is determined by the crystal characteristics. If the center frequency is lower than the target frequency, C×40 and C×60 can be added to change the resonant frequency. And R×40 and R×60 can be added to adjust the filter Q factor. Internally, pin XO is linked to pin XI by a phase-inverted signal passed through a capacitor, which cancels the high-frequency components that pass through the crystal parallel capacitances.

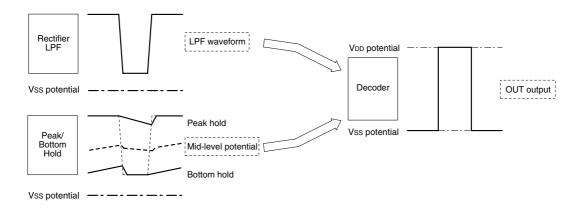
Detector Circuit

The amplified signal is full-wave rectified and passed through a lowpass filter detector. The detector output is input to peak hold (pin CP) and bottom hold (pin CB) circuits to form the decoder reference potentials and peak hold potential for AGC control.



Decoder Circuit

The detector output and peak/bottom hold mid-level potential reference are used to decode the time code signal, which is output on pin OUT. The output is active-LOW, so that the output is LOW when the input amplitude is HIGH.



Standby Function

When PON is open (or HIGH), the device is in standby mode and the current consumption is reduced. Receiver operation starts when PON goes LOW.

PON	Mode	OUT
Opt HIGH)	Standby	HIGH
LOW	Operating	Time code

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NC0304BE 2010.09